

Monolithic CMOS Analog Multiplexers

ABSOLUTE MAXIMUM RATINGS

Voltage Referenced to V-

V+	+44V
GND	+25V
Digital Inputs, V _S and V _D (Note 1)	-2V to (V+ + 2V) or 20mA, whichever occurs first
Current (any terminal, except S or D)	30mA
Continuous Current, S or D	20mA
Peak Current, S or D (pulsed at 1ms, 10% duty cycle max)	40mA
Continuous Power Dissipation (T _A = +70°C)	
Plastic DIP (derate 10.53mW/°C above +70°C)	842mW
Narrow SO (derate 8.70mW/°C above +70°C)	696mW
Wide SO (derate 9.52mW/°C above +70°C)	762mW
CERDIP (derate 10.00mW/°C above +70°C)	800mW

Operating Temperature Ranges:

DG50_ACJ/CWE	0°C to +70°C
DG50_ABK	-20°C to +85°C
DG50_ADJ/DY/EWE	-40°C to +85°C
DG50_AAK/MY	-55°C to +125°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C
Soldering Temperature (reflow)	
PDIP, Wide SO, Narrow SO, CERDIP containing lead(Pb)	+240°C
PDIP, Wide SO, Narrow SO lead(Pb)-free	+260°C

Note 1: Signals on S₋ or D₋ exceeding V+ or V- are clamped by internal diodes. Limit forward-diode current to maximum current ratings

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

(V+ = 15V, V- = -15V, V_{GND} = 0V, T_A = +25°C, unless otherwise noted.)

PARAMETER		SYMBOL	CONDITIONS		DG508AA/M DG509AA/M			DG508AD/E/B/C DG509AD/E/B/C			UNITS		
					MIN	TYP	MAX	MIN	TYP	MAX			
SWITCH													
Analog Signal		VANALOG			-15		+15		-15		+15		V
Drain-Source On-Resistance		RDS(ON)	Sequence each switch on, VA_L = 0.8V, VA_H = 2.4V (Note 4)	VD = 10V, IS = -200μA	170		400		170		450		Ω
				VD = -10V, IS = 200μA	130		400		130		450		
Greatest Change in Drain-Source On-Resistance Between Channels		ΔRDS(ON)	$\Delta R_{DS(ON)} = \left(\frac{R_{DS(ON) \text{ max}} - R_{DS(ON) \text{ min}}}{R_{DS(ON)}} \right)$ -10V ≥ VS ≥ 10V		6			6			%		
Source Off-Leakage Current		IS(OFF)	VEN = 0V	VS = 10V, VD = -10V	0.002		0.5		0.002		1		nA
				VS = -10V, VD = 10V	-0.5		-0.005		-1		-0.005		
Drain Off-Leakage Current	DG508A	ID(OFF)	VEN = 0V	VD = 10V, VS = -10V	0.01		2		0.01		5		nA
	VD = -10V, VS = 10V			-2		-0.015		-5		-0.015			
	VD = 10V, VS = -10V			0.005		2		0.005		5			
	VD = -10V, VS = 10V			-2		-0.008		-5		-0.008			
Drain On-Leakage Current	DG508A	ID(ON)	Sequence each switch on, VA_L = 0.8V VA_H = 2.4V (Note 2)	VS(all) = VD = 10V	0.015		2		0.015		5		nA
	VS(all) = VD = -10V			-2		-0.03		-5		-0.03			
	VS(all) = VD = 10V			0.007		2		0.007		5			
	VS(all) = VD = -10V			-2		-0.015		-5		-0.015			

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DG508A/DG509A

ELECTRICAL CHARACTERISTICS (continued)

(V₊ = 15V, V₋ = -15V, V_{GND} = 0V, T_A = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		DG508AA/M DG509AA/M			DG508AD/E/B/C DG509AD/E/B/C			UNITS
				MIN	TYP	MAX	MIN	TYP	MAX	
LOGIC INPUT										
Logic Input Current, Input Voltage High	I _{AH}	V _{A-} = 2.4V		-10	-		10	-0.002		μA
		V _{A-} = 15V			0.006	10		0.006	10	
Logic Input Current, Input Voltage Low	I _{AL}	All V _{A-} = 0V	V _{EN} = 2.4V	-10	-		10	-0.002		μA
			V _{EN} = 0V	-10	-		-10	-0.002		
DYNAMIC										
Multiplexer Switching	t _{transition}	Figure 1			0.6	1.0		0.6	1.0	μs
Break-Before-Make Interval	t _{OPEN}	Figure 3			0.2			0.2		μs
Enable Turn-On Time	t _{ON(EN)}	Figure 2			0.4	1.0		0.4	1.5	μs
Enable Turn-Off Time	t _{OFF(EN)}	Figure 2			0.2	0.7		0.2	1.0	μs
Off-Isolation	OIRR	V _{EN} = 0V, R _L = 1kΩ, C _L = 15pF, V _S = 7V _{RMS} f = 500kHz (Note 3)			68			68		dB
Source Off-Capacitance	C _{S(OFF)}	V _S = 0V, V _{EN} = 0V, f = 140kHz			5			5		pF
Drain Off- Capacitanc	IDG508A	C _{D(OFF)}	V _S = 0V, V _{EN} = 0V, f = 140kHz		25			25		pF
	DGS09A				12			12		
SUPPLY										
Positive Supply Current	I ₊	V _{EN} = 2.4V, all V _{A-} = 0V or 2.4V			0.02	0.2		0.02	0.2	mA
Negative Supply Current	I ₋	V _{EN} = 2.4V, all V _{A-} = 0V or 2.4V		-0.1	-0.01		-0.1	-0.01		mA
Positive Supply Current in Standby	I ₊	V _{EN} = 0V, all V _{A-} = 0V or 2.4V			0.02	0.2		0.02	0.2	mA
Negative Supply Current in Standby	I ₋	V _{EN} = 0V, all V _{A-} = 0V or 2.4V		-0.1	-0.01		-0.1	-0.01		mA
Power-Supply Range for Continuous Operation	V ₋ , V ₊	(Notes 4, 5)		±4.5		±18.0	±4.5		±18.0	V

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ELECTRICAL CHARACTERISTICS

(V₊ = 15V, V_{GND} = 0V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted.)

PARAMETER		SYMBOL	CONDITIONS		DG508AA/M DG509AA/M			DG508AD/E/B/C DG509AD/E/B/C			UNITS
					MIN	TYP	MAX	MIN	TYP	MAX	
SWITCH											
Analog Signal Range		V _{ANALOG}			-15	+15		-15	+15	V	
Drain-Source On-Resistance		R _{DS(ON)}	Sequence each switch on, V _{A_L} = 0.8V, V _{A_H} = 2.4V	V _D = 10V, I _S = -200μA	500		550		Ω		
				V _D = -10V, I _S = 200μA	500		550				
Source Off-Leakage Current		I _{S(OFF)}	V _{EN} = 0V	V _S = 10V, V _D = -10V	+50		+50		nA		
				V _S = -10V, V _D = -10V	-50		-50				
Drain Off-Leakage Current	DG508A	I _{D(OFF)}	V _{EN} = 0V	V _D = 10V, V _S = -10V	+200		+100		nA		
	V _D = -10V, V _S = -10V			-200		-200					
	DG509A			V _D = 10V, V _S = -10V	+200		+100				
	V _D = -10V, V _S = -10V			-100		-100					
Drain On-Leakage Current	DG508A	I _{D(ON)}	Sequence each switch on, V _{A_L} = 0.8V, V _{A_H} = 2.4V (Note 2)	V _{S(all)} = V _D = 10V	+200		+100		nA		
	V _{S(all)} = V _D = -10V			-200		-100					
	DG509A			V _{S(all)} = V _D = 10V	+100		+100				
	V _{S(all)} = V _D = -10V			-100		-100					
LOGIC INPUT											
Logic Input Current, Input Voltage High		I _{AH}	V _{A_} = 2.4V		-30		-30		μA		
			V _{A_} = 15V		+30		+30				
Logic Input Current, Input Voltage Low		I _{AL}	All V _{A_} = 0V	V _{EN} = 2.4V		-30		-30		μA	
				V _{EN} = 0V		-30		-30			

Note 2: I_{D(ON)} is leakage from driver into on switch.

Note 3: Off-isolation = $20 \log \frac{|V_S|}{|V_D|}$

V_S = input to off switch,
V_D = output due to V_S.

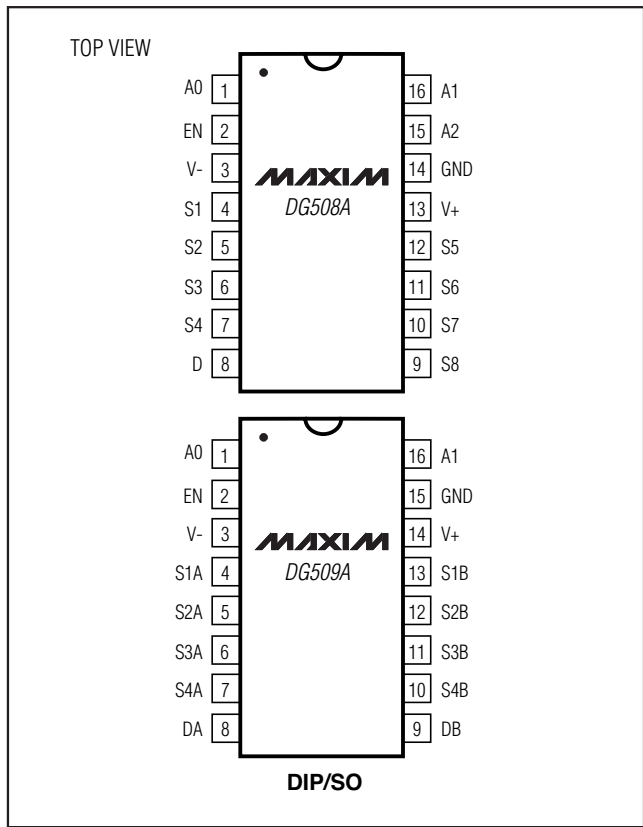
Note 4: Electrical characteristics (such as on-resistance) change when power supplies other than ±15V are used.

Note 5: For designs requiring single 5V or dual ±5V operation, refer to Maxim's improved MAX338 and MAX339. Minimum operating voltage for DG508ADY/MY and DG509ADY/MY is ±9V.

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DG508A/DG509A

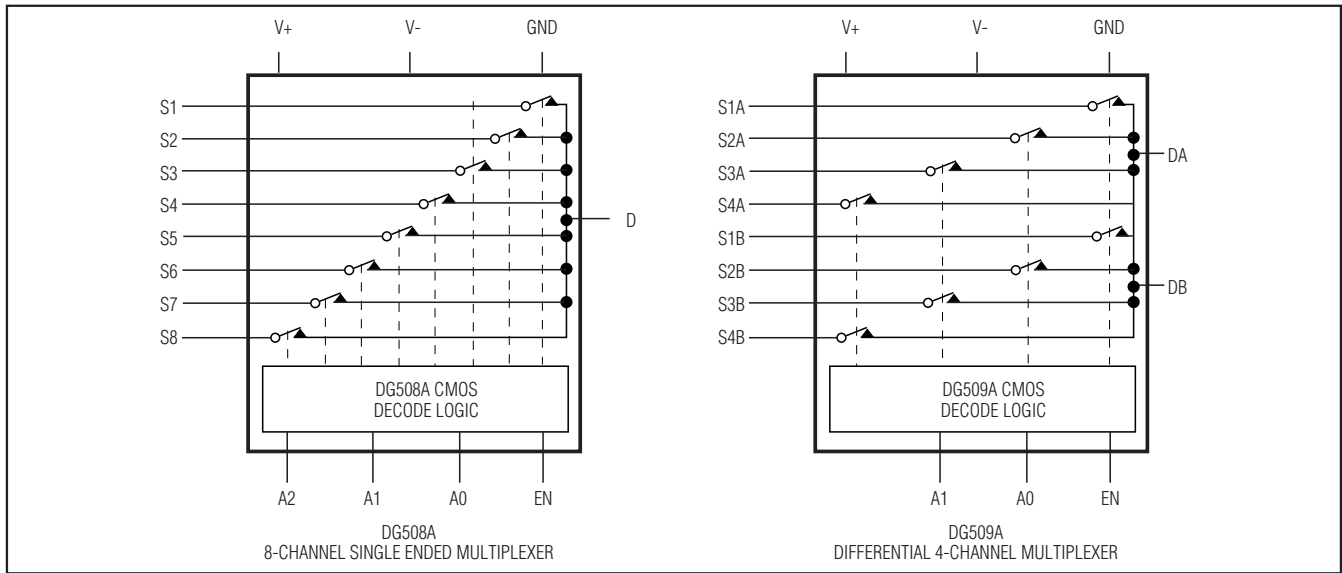
Pin Configurations



Pin Descriptions

PIN		NAME	FUNCTION
DG508A DIP/SO	DG509A DIP/SO		
1, 15, 16	—	A0, A2, A1	Address Input
—	1, 16	A0, A1	Address Input
2	2	EN	Enable
3	3	V-	Negative-Supply Voltage Input
4–7	—	S1–S4	Analog Inputs, Bidirectional
—	4–7	S1A–S4A	Analog Inputs, Bidirectional
8	—	D	Analog Outputs, Bidirectional
—	8, 9	DA, DB	Analog Outputs, Bidirectional
9–12	—	S8–S5	Analog Inputs, Bidirectional
—	10–13	S4B–S1B	Analog Inputs, Bidirectional
13	14	V+	Positive-Supply Voltage Input
14	15	GND	Ground

Functional Diagrams



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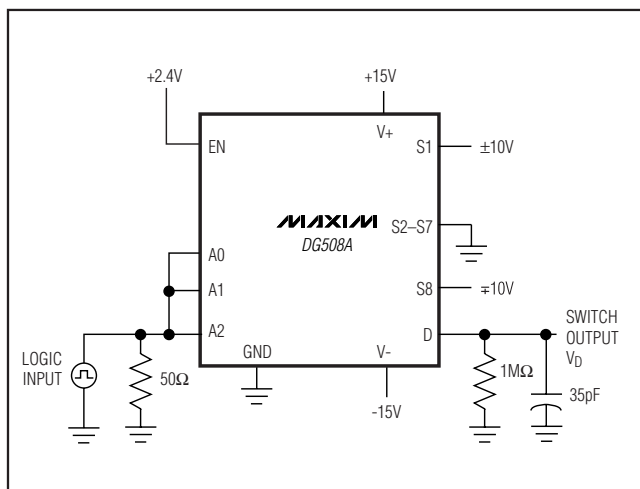


Figure 1a. Switching-Time Test Circuit

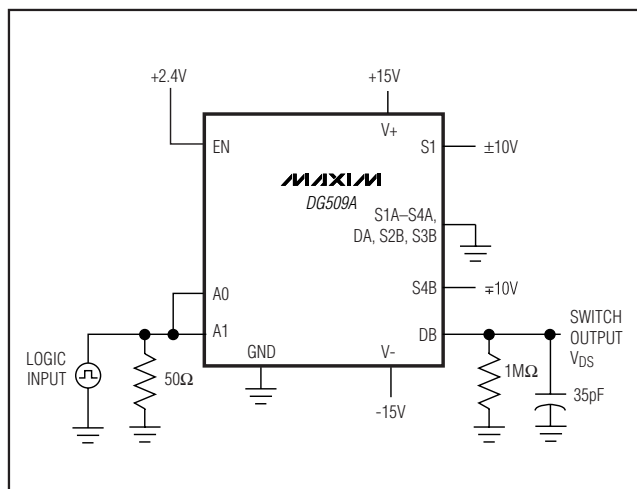


Figure 1b. Switching-Time Test Circuit

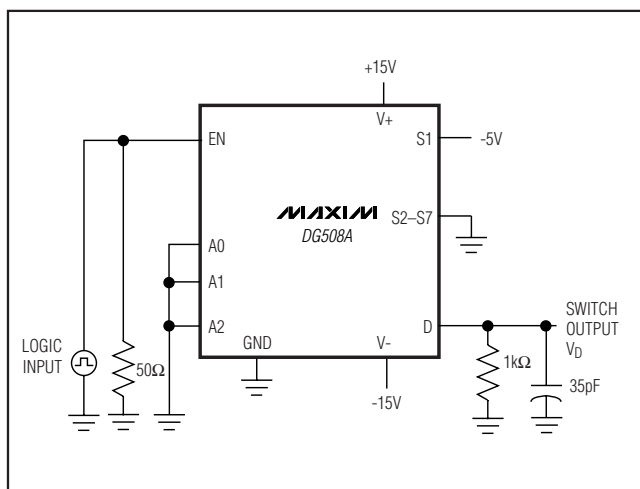


Figure 2a. DG508A Enable-Time Test Circuit

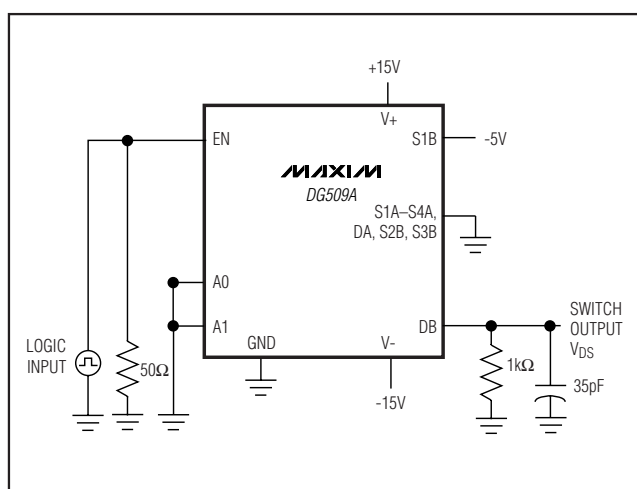


Figure 2b. DG509A Enable-Time Test Circuit

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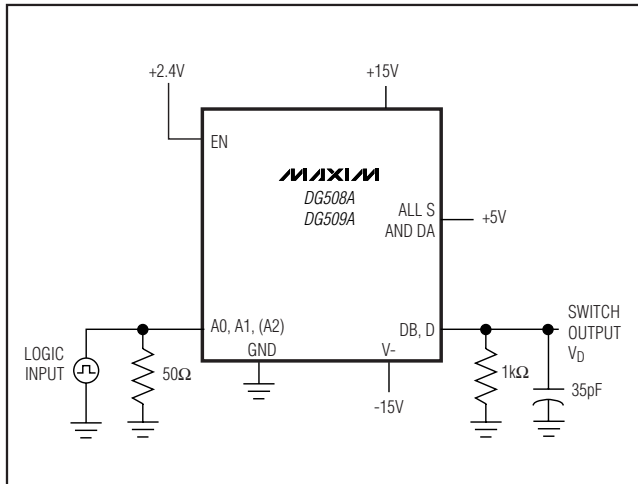


Figure 3. Break-Before-Make Test Circuit

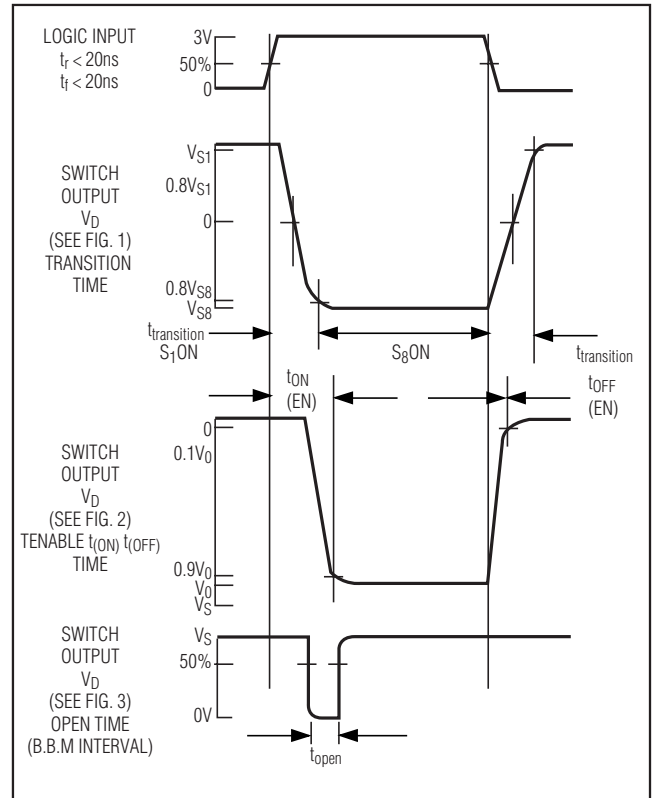


Figure 4. Timing Diagram for Figures 1, 2, and 3

Table 1a. DG508A Truth Table

A2	A1	A0	EN	ON SWITCH
X	X	X	0	NONE
0	0	0	1	1
0	0	1	1	2
0	1	0	1	3
0	1	1	1	4
1	0	0	1	5
1	0	1	1	6
1	1	0	1	7
1	1	1	1	8

X = Don't care.

Table 1b. DG509A Truth Table

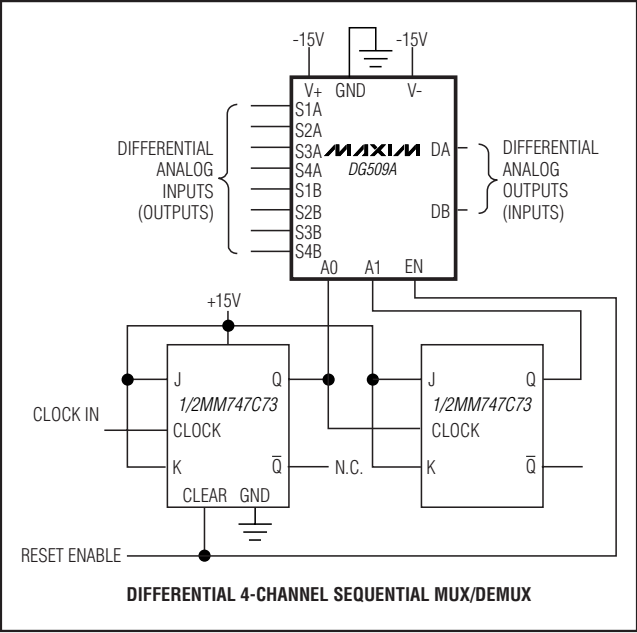
A1	A0	EN	ON SWITCH
X	X	0	NONE
0	0	1	1
0	1	1	2
1	0	1	3
1	1	1	4

X = Don't care.

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Typical Operating Circuits (continued)



Package Information

For the latest package outline information and land patterns, go to www.maxim-ic.com/packages. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	DOCUMENT NO.
16 Plastic DIP	P16-1	21-0043
16 Wide SO	W16-2	21-0042
16 Narrow SO	S16-5	21-0041
16 Cerdip	J16-3	21-0045

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Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
4	5/10	Updated the "Drain-Source On-Resistance" parameter for both the $T_A = +25^{\circ}\text{C}$ and $T_A = T_{\text{MIN}}$ to T_{MAX} conditions.	2, 4
		Deleted the QFN package from the <i>Ordering Information</i> , <i>Absolute Maximum Ratings</i> , <i>Pin Configurations</i> , <i>Pin Descriptions</i> , and <i>Package Information</i> sections.	1, 2, 5, 8
		Added the DG508AMY/PR and DG509AMY/PR parts to the <i>Ordering Information</i> table.	1

DG508A/DG509A

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